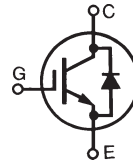


## High Voltage IGBTs w/Diode

## IXGH40N120B2D1 IXGT40N120B2D1



$$V_{CES} = 1200V$$

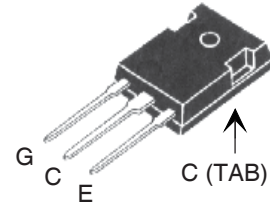
$$I_{C110} = 40A$$

$$V_{CE(sat)} \leq 3.5V$$

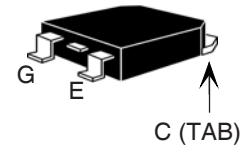
$$t_{fi(typ)} = 140ns$$

| Symbol                  | Test Conditions                                           | Maximum Ratings      |            |
|-------------------------|-----------------------------------------------------------|----------------------|------------|
| $V_{CES}$               | $T_C = 25^\circ C$ to $150^\circ C$                       | 1200                 | V          |
| $V_{CGR}$               | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GE} = 1M\Omega$ | 1200                 | V          |
| $V_{GES}$               | Continuous                                                | $\pm 20$             | V          |
| $V_{GEM}$               | Transient                                                 | $\pm 30$             | V          |
| $I_{C25}$               | $T_C = 25^\circ C$ (Limited by Lead)                      | 75                   | A          |
| $I_{C110}$              | $T_C = 110^\circ C$                                       | 40                   | A          |
| $I_{F110}$              | $T_C = 110^\circ C$                                       | 25                   | A          |
| $I_{CM}$                | $T_C = 25^\circ C$ , 1ms                                  | 200                  | A          |
| <b>SSOA<br/>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ C$ , $R_G = 2\Omega$ | $I_{CM} = 80$        | A          |
|                         | Clamped Inductive Load                                    | @ $0.8 \leq V_{CES}$ | V          |
| $P_C$                   | $T_C = 25^\circ C$                                        | 380                  | W          |
| $T_J$                   |                                                           | -55 ... +150         | $^\circ C$ |
| $T_{JM}$                |                                                           | 150                  | $^\circ C$ |
| $T_{stg}$               |                                                           | -55 ... +150         | $^\circ C$ |
| $T_L$                   | 1.6mm (0.062 in.) from Case for 10s                       | 300                  | $^\circ C$ |
| $T_{SOLD}$              | Plastic Body for 10 seconds                               | 260                  | $^\circ C$ |
| $M_d$                   | Mounting Torque (TO-247)                                  | 1.13/10              | Nm/lb.in.  |
| <b>Weight</b>           | TO-247                                                    | 6                    | g          |
|                         | TO-268                                                    | 4                    | g          |

### TO-247 (IXGH)



### TO-268 (IXGT)



G = Gate      C = Collector  
E = Emitter    TAB = Collector

### Features

- International Standard Packages
- IGBT and Anti-Parallel FRED for Resonant Power Supplies
  - Induction Heating
  - Rice Cookers
- Square RBSOA
- Fast Recovery Exptaxial Diode (FRED)
  - Soft Recovery with Low  $I_{RM}$

### Advantages

- High Power Density
- Low Gate Drive Requirement

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ Unless Otherwise Specified) | Characteristic Values |      |              |
|---------------|---------------------------------------------------------------------|-----------------------|------|--------------|
|               |                                                                     | Min.                  | Typ. | Max.         |
| $V_{GE(th)}$  | $I_C = 250\mu A$ , $V_{CE} = V_{GE}$                                | 3.0                   |      | 5.0 V        |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$                                  |                       |      | 100 $\mu A$  |
|               | $T_J = 125^\circ C$                                                 |                       |      | 3 mA         |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                  |                       |      | $\pm 100$ nA |
| $V_{CE(sat)}$ | $I_C = 40A$ , $V_{GE} = 15V$ , Note 1                               | 2.9                   | 3.5  | V            |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                                                                     | Characteristic Values |      |                         |
|--------------|-----------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|-------------------------|
|              |                                                                                                                                               | Min.                  | Typ. | Max.                    |
| $g_{fs}$     | $I_C = 40\text{A}$ , $V_{CE} = 10\text{V}$ , Note 1                                                                                           | 23                    | 37   | S                       |
| $C_{ies}$    | $V_{CE} = 25\text{V}$ , $V_{GE} = 0\text{V}$ , $f = 1\text{MHz}$                                                                              |                       | 3360 | pF                      |
| $C_{oes}$    |                                                                                                                                               |                       | 190  | pF                      |
| $C_{res}$    |                                                                                                                                               |                       | 63   | pF                      |
| $Q_g$        | $I_C = 40\text{A}$ , $V_{GE} = 15\text{V}$ , $V_{CE} = 0.5 \cdot V_{CES}$                                                                     |                       | 138  | nC                      |
| $Q_{ge}$     |                                                                                                                                               |                       | 20   | nC                      |
| $Q_{gc}$     |                                                                                                                                               |                       | 48   | nC                      |
| $t_{d(on)}$  | Inductive load, $T_J = 25^\circ\text{C}$<br>$I_C = 40\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 960\text{V}$ , $R_G = 2\Omega$<br>Note 2  |                       | 21   | ns                      |
| $t_{ri}$     |                                                                                                                                               |                       | 55   | ns                      |
| $E_{on}$     |                                                                                                                                               |                       | 4.5  | mJ                      |
| $t_{d(off)}$ |                                                                                                                                               |                       | 290  | ns                      |
| $t_{fi}$     |                                                                                                                                               |                       | 140  | ns                      |
| $E_{off}$    |                                                                                                                                               |                       | 3.0  | 6.0 mJ                  |
| $t_{d(on)}$  | Inductive load, $T_J = 125^\circ\text{C}$<br>$I_C = 40\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 960\text{V}$ , $R_G = 2\Omega$<br>Note 2 |                       | 21   | ns                      |
| $t_{ri}$     |                                                                                                                                               |                       | 58   | ns                      |
| $E_{on}$     |                                                                                                                                               |                       | 6.5  | mJ                      |
| $t_{d(off)}$ |                                                                                                                                               |                       | 350  | ns                      |
| $t_{fi}$     |                                                                                                                                               |                       | 420  | ns                      |
| $E_{off}$    |                                                                                                                                               |                       | 8.3  | mJ                      |
| $R_{thJC}$   |                                                                                                                                               |                       |      | 0.33 $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                               |                       | 0.21 | $^\circ\text{C/W}$      |

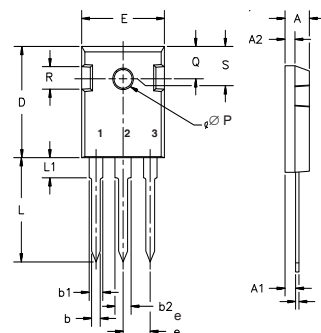
## Reverse Diode (FRED)

| Symbol     | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                             | Characteristic Values |      |                        |
|------------|---------------------------------------------------------------------------------------------------------|-----------------------|------|------------------------|
|            |                                                                                                         | Min.                  | Typ. | Max.                   |
| $V_F$      | $I_F = 30\text{A}$ , $V_{GE} = 0\text{V}$                                                               |                       |      | 2.8 V                  |
|            | $T_J = 150^\circ\text{C}$                                                                               |                       | 1.6  | V                      |
| $I_{RM}$   | $I_F = 30\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$ ,<br>$V_R = 300\text{V}$ , $V_{GE} = 0\text{V}$ |                       |      | 4 A                    |
| $t_{rr}$   |                                                                                                         |                       | 100  | ns                     |
| $R_{thJC}$ |                                                                                                         |                       |      | 0.9 $^\circ\text{C/W}$ |

Note 1: Pulse Test,  $t \leq 300\mu\text{s}$ , Duty Cycle,  $d \leq 2\%$ .

2. Switching Times may Increase for  $V_{CE}$  (Clamp)  $> 0.8 \cdot V_{CES}$ ,  
Higher  $T_J$  or Increased  $R_G$ .

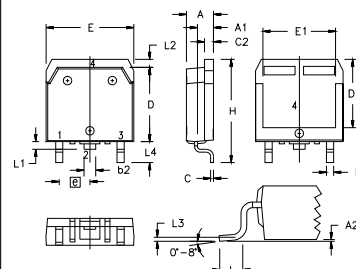
## TO-247 (IXGH) Outline



Terminals: 1 - Gate  
2 - Drain  
3 - Source  
Tab - Drain

| Dim.           | Min.     | Max.  | Min.     | Max.  |
|----------------|----------|-------|----------|-------|
| A              | 4.7      | 5.3   | .185     | .209  |
| A <sub>1</sub> | 2.2      | 2.54  | .087     | .102  |
| A <sub>2</sub> | 2.2      | 2.6   | .059     | .098  |
| b              | 1.0      | 1.4   | .040     | .055  |
| b <sub>1</sub> | 1.65     | 2.13  | .065     | .084  |
| b <sub>2</sub> | 2.87     | 3.12  | .113     | .123  |
| C              | .4       | .8    | .016     | .031  |
| D              | 20.80    | 21.46 | .819     | .845  |
| E              | 15.75    | 16.26 | .610     | .640  |
| e              | 5.20     | 5.72  | 0.205    | 0.225 |
| L              | 19.81    | 20.32 | .780     | .800  |
| L1             |          | 4.50  |          | .177  |
| ØP             | 3.55     | 3.65  | .140     | .144  |
| Q              | 5.89     | 6.40  | 0.232    | 0.252 |
| R              | 4.32     | 5.49  | .170     | .216  |
| S              | 6.15 BSC |       | .242 BSC |       |

## TO-268 (IXGT) Outline



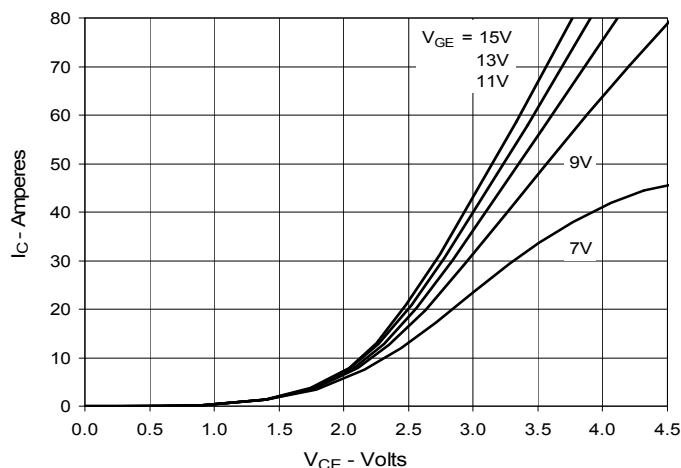
| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .193     | .201 | 4.90        | 5.10  |
| A1  | .106     | .114 | 2.70        | 2.90  |
| A2  | .001     | .010 | 0.02        | 0.25  |
| b   | .045     | .057 | 1.15        | 1.45  |
| b2  | .075     | .083 | 1.90        | 2.10  |
| C   | .016     | .026 | 0.40        | 0.65  |
| C2  | .057     | .063 | 1.45        | 1.60  |
| D   | .543     | .551 | 13.80       | 14.00 |
| D1  | .488     | .500 | 12.40       | 12.70 |
| E   | .624     | .632 | 15.85       | 16.05 |
| E1  | .524     | .535 | 13.30       | 13.60 |
| e   | .215 BSC |      | 5.45 BSC    |       |
| H   | .736     | .752 | 18.70       | 19.10 |
| L   | .094     | .106 | 2.40        | 2.70  |
| L1  | .047     | .055 | 1.20        | 1.40  |
| L2  | .039     | .045 | 1.00        | 1.15  |
| L3  | .010 BSC |      | 0.25 BSC    |       |
| L4  | .150     | .161 | 3.80        | 4.10  |

IXYS Reserves the Right to Change Limits, Test Conditions and Dimensions.

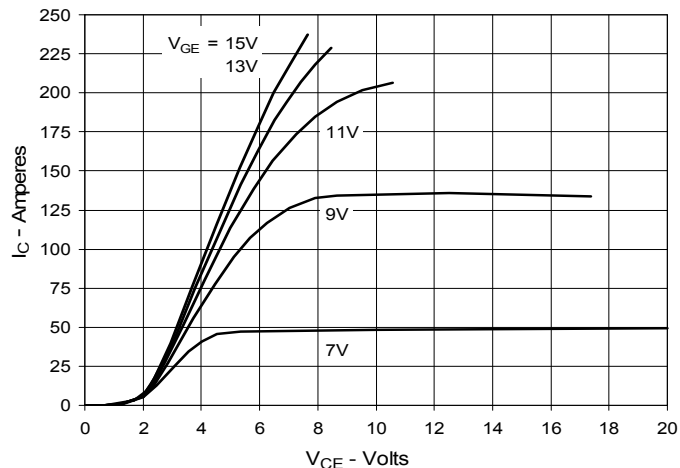
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |             |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

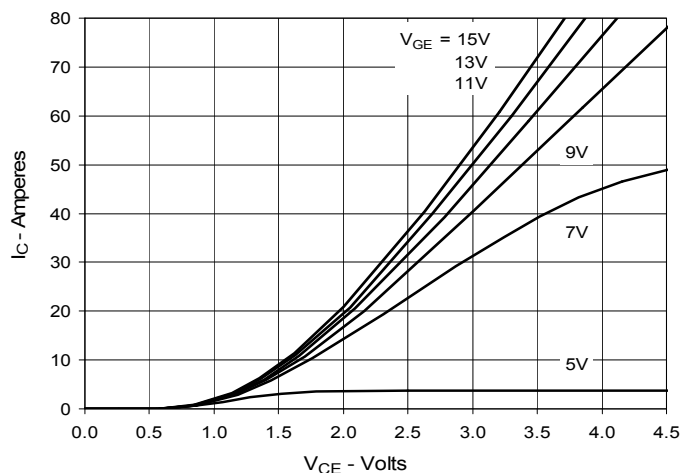
**Fig. 1. Output Characteristics**  
**@ 25°C**



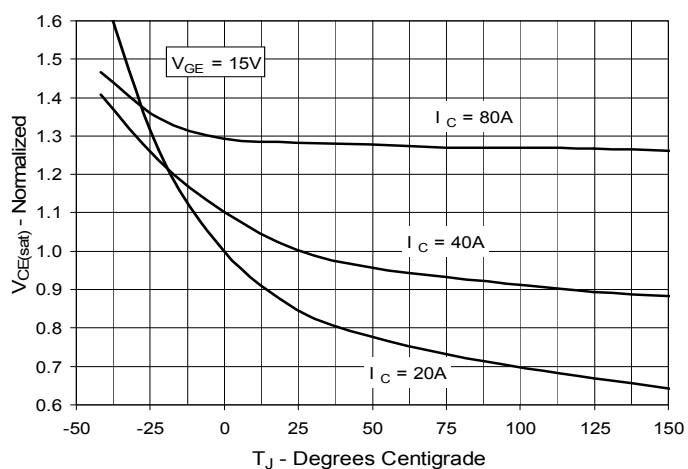
**Fig. 2. Extended Output Characteristics**  
**@ 25°C**



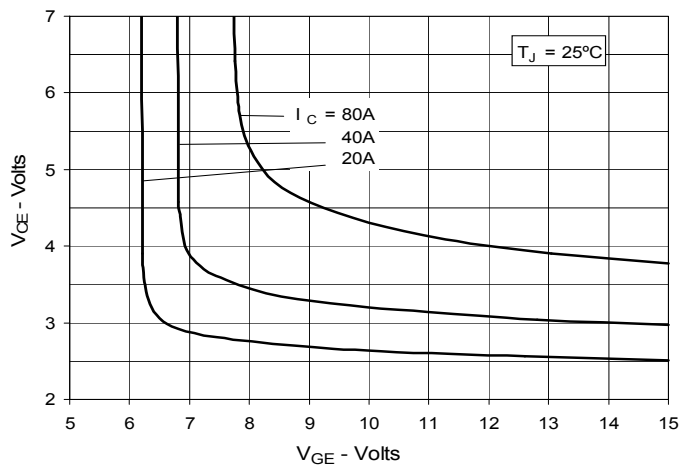
**Fig. 3. Output Characteristics**  
**@ 125°C**



**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**



**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**



**Fig. 6. Input Admittance**

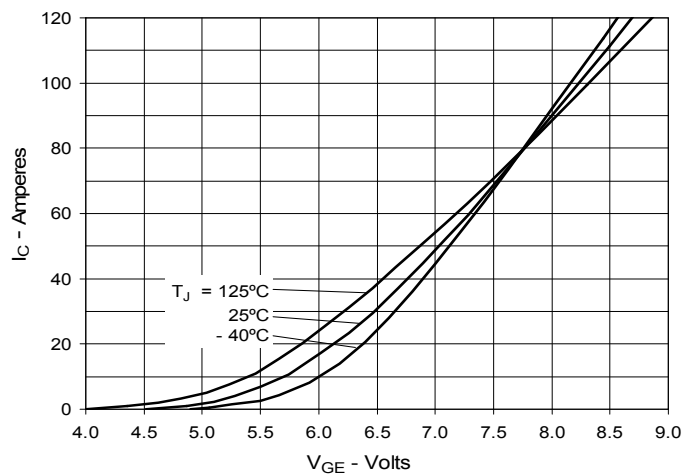


Fig. 7. Transconductance

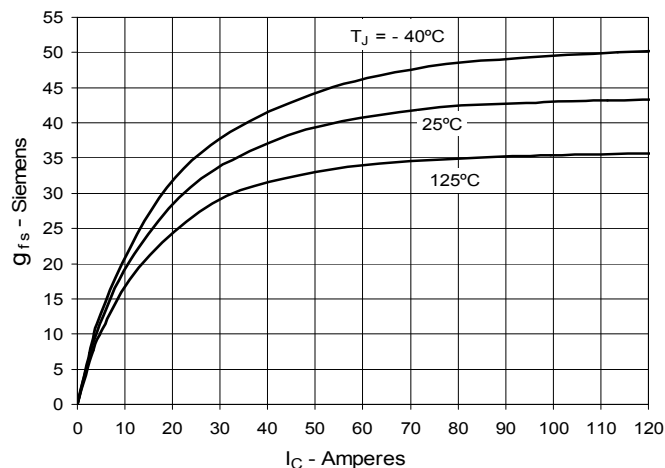


Fig. 8. Gate Charge

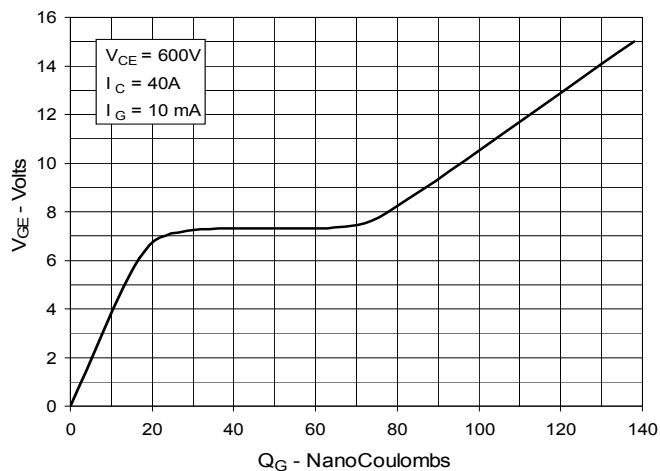


Fig. 9. Capacitance

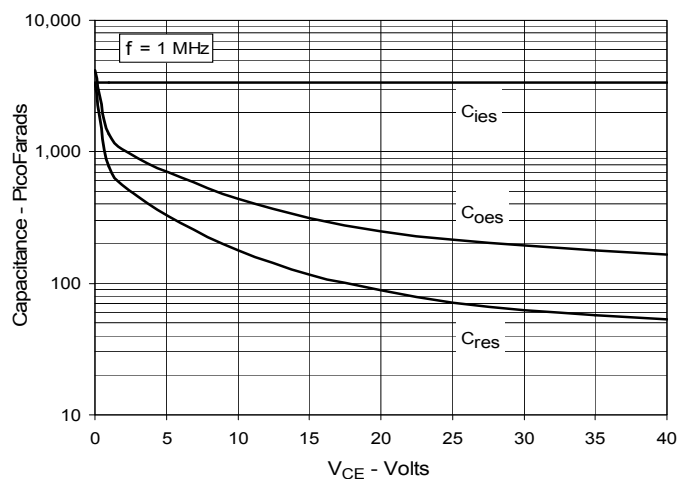


Fig. 10. Reverse-Bias Safe Operating Area

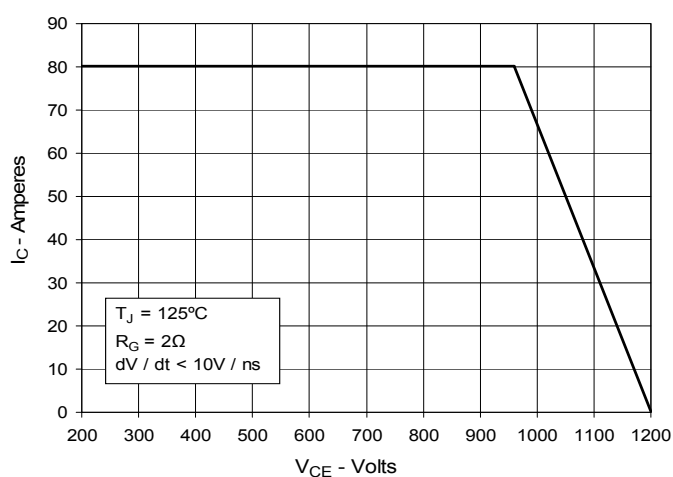
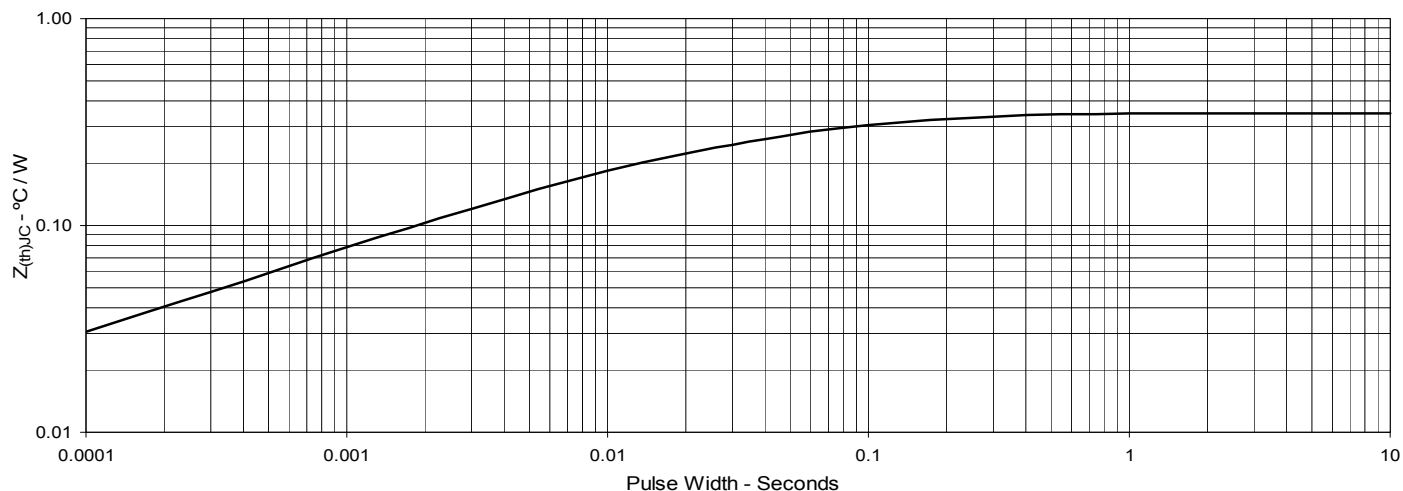
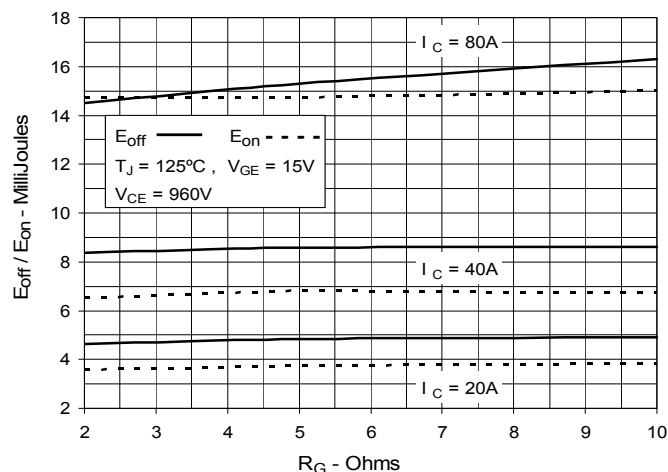
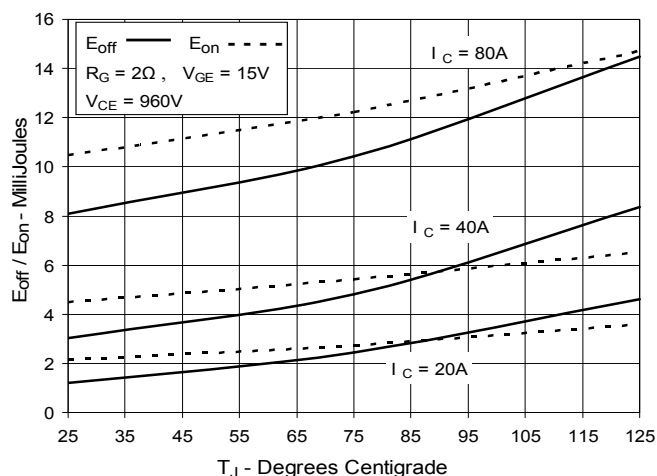
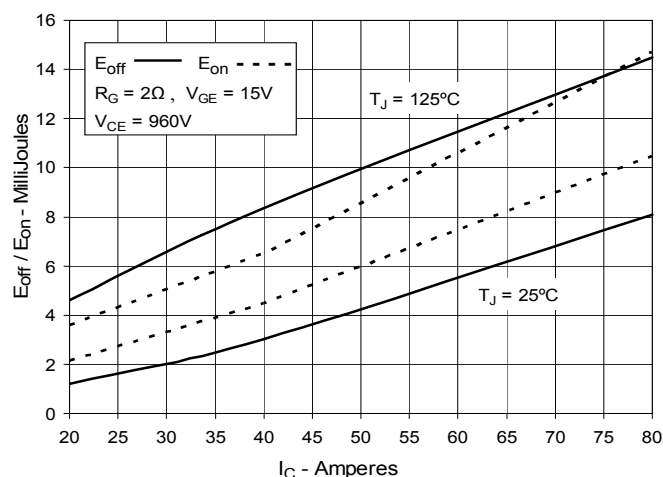
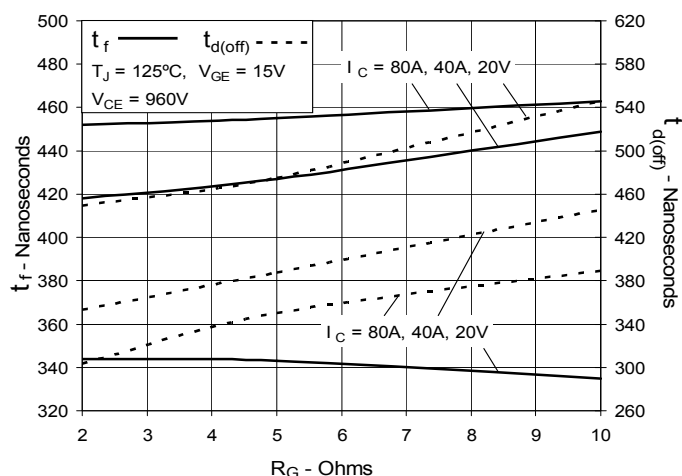
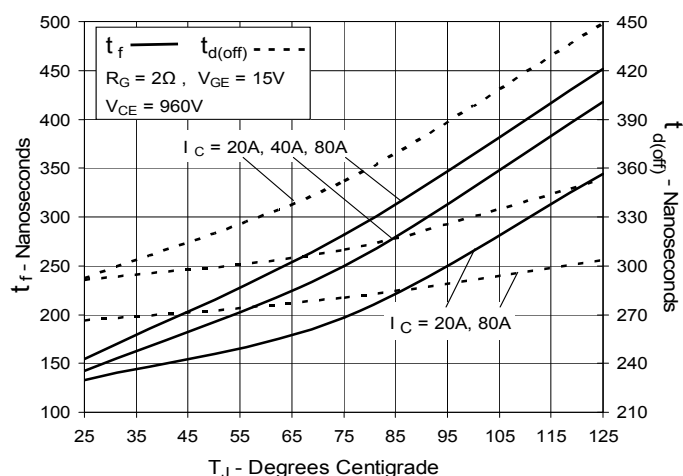
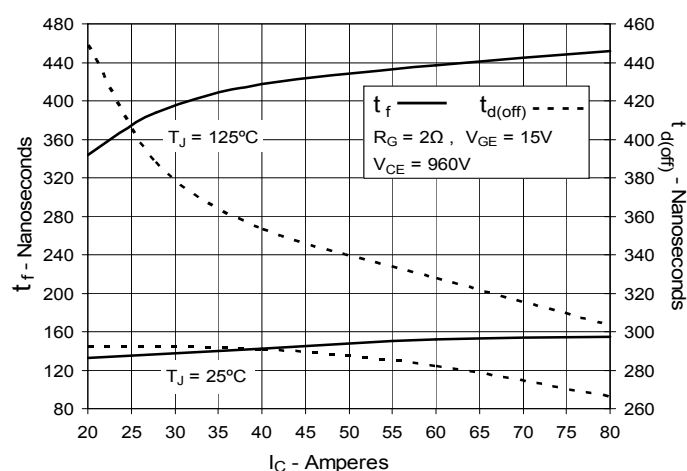
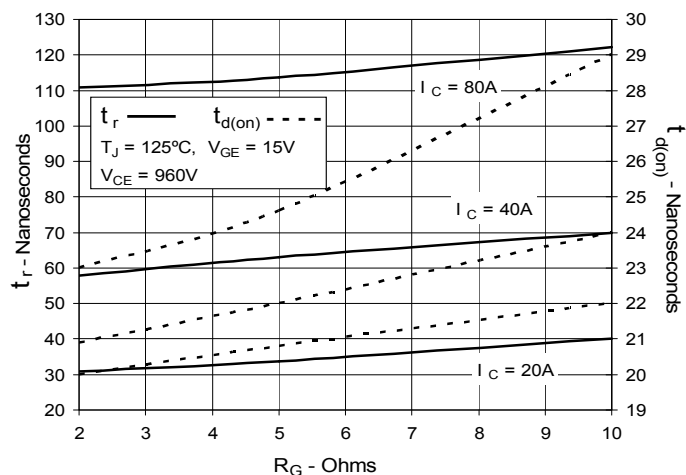


Fig. 11. Maximum Transient Thermal Impedance

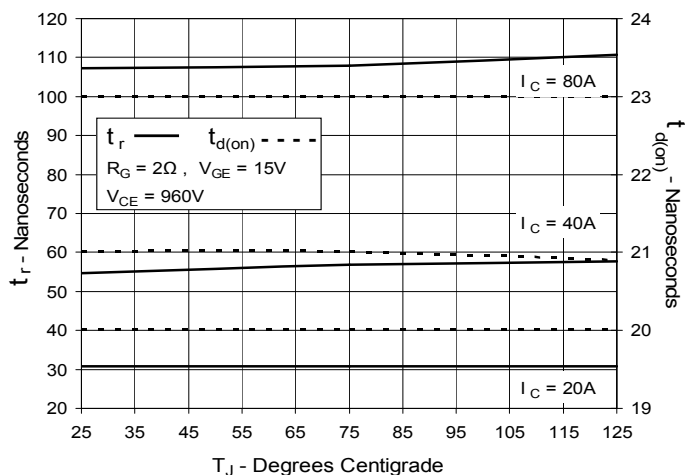


**Fig. 12. Inductive Switching Energy Loss vs. Gate Resistance**

**Fig. 13. Inductive Switching Energy Loss vs. Junction Temperature**

**Fig. 14. Inductive Switching Energy Loss vs. Collector Current**

**Fig. 15. Inductive Turn-off Switching Times vs. Gate Resistance**

**Fig. 16. Inductive Turn-off Switching Times vs. Junction Temperature**

**Fig. 17. Inductive Turn-off Switching Times vs. Collector Current**


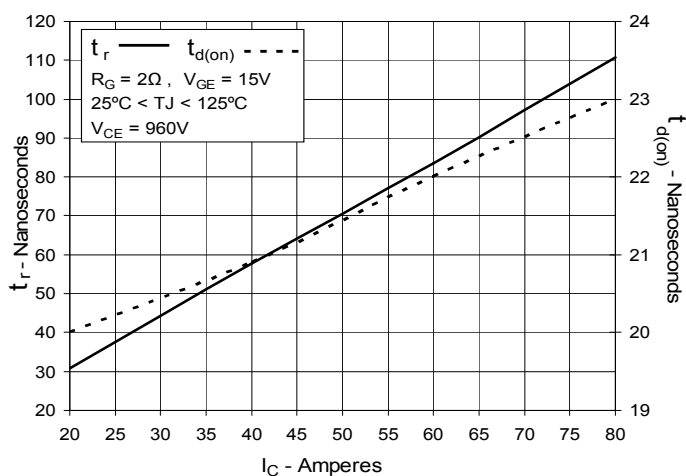
**Fig. 18. Inductive Turn-on Switching Times vs. Gate Resistance**



**Fig. 19. Inductive Turn-on Switching Times vs. Junction Temperature**



**Fig. 20. Inductive Turn-on Switching Times vs. Collector Current**



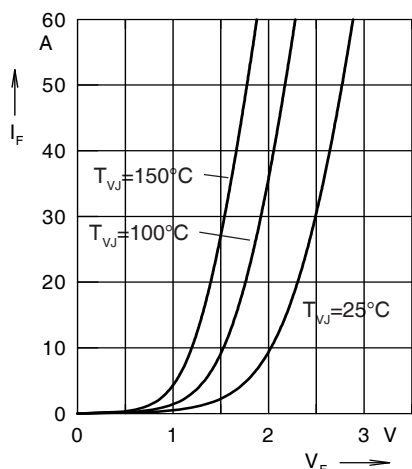


Fig. 21. Forward current  $I_F$  versus  $V_F$

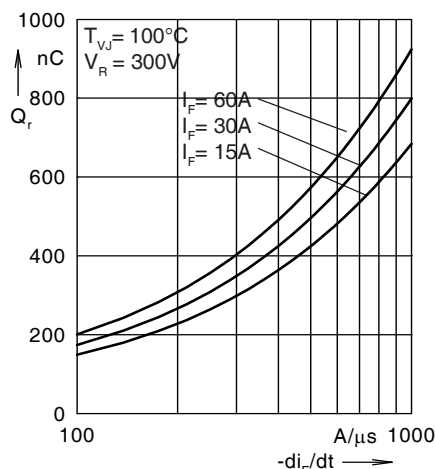


Fig. 22. Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

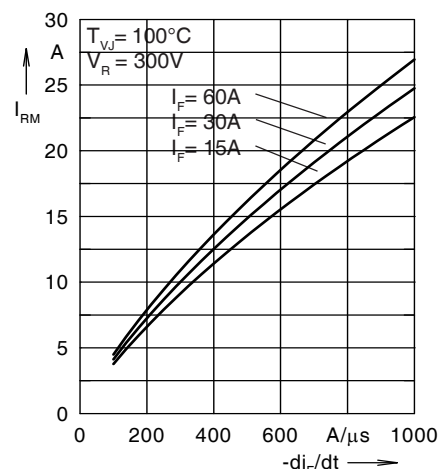


Fig. 23. Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

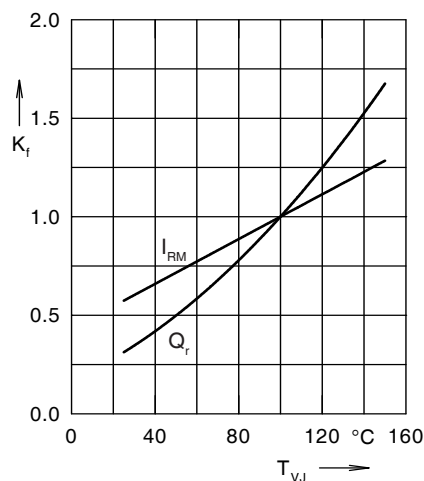


Fig. 24. Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

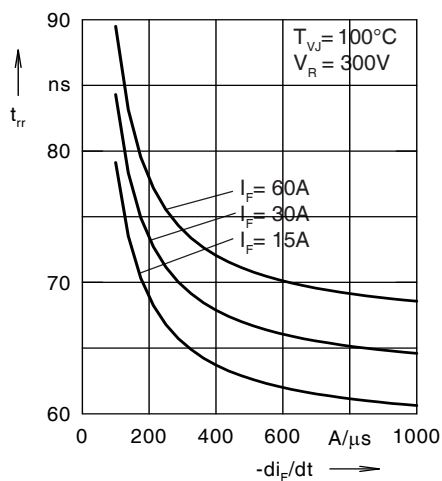


Fig. 25. Recovery time  $t_{rr}$  versus  $-di_F/dt$

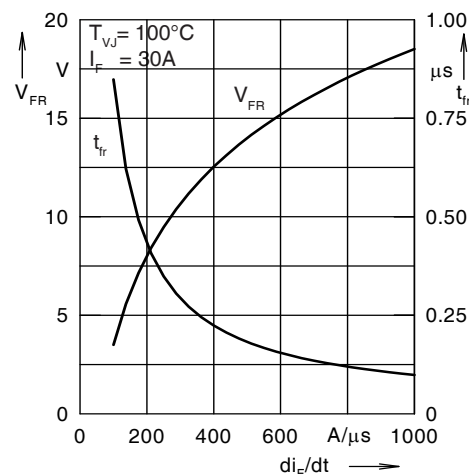


Fig. 26. Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

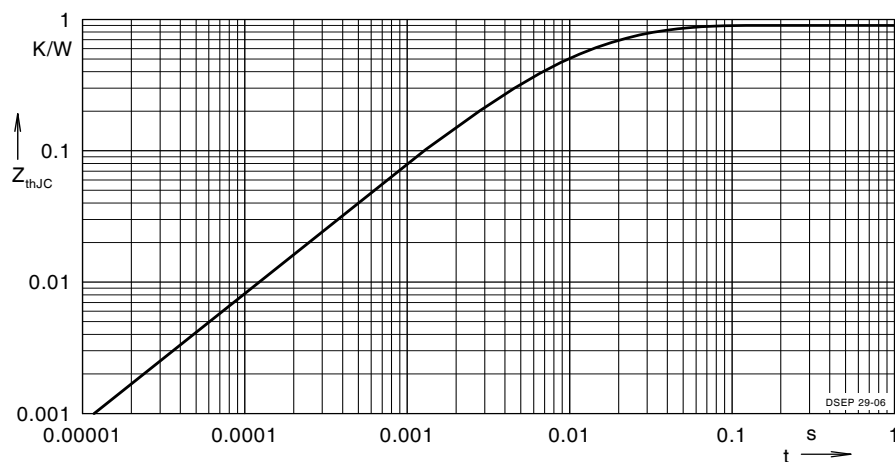


Fig. 27. Transient thermal resistance junction to case

## Constants for $Z_{thJC}$ calculation

| i | $R_{th}$ (°C/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.465           | 0.0052    |
| 2 | 0.179           | 0.0003    |
| 3 | 0.256           | 0.0397    |



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